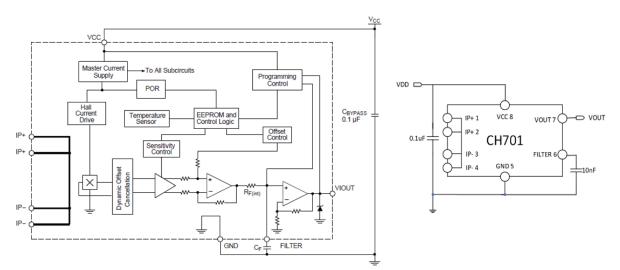


CH701

3000V_{RMS} Isolation, Hall Current Sensor IC in SOIC-8 Package

Features

- Reinforced isolation: 3000 V_{RMS}
- Total output error: ±1.5% typical
- Primary conductor resistance: **0.8 m** Ω
- Single supply: 3.3V or 5V
- Output voltage proportional to AC or DC current: ±5A, ±10A, ±20A, ±30A, ±40A, ±50A
- -3dB bandwidth: 120 kHz
- Response time: 4 µs
- Ratio-metric output from supply voltage
- Adjustable bandwidth and resolution with a filter pin
- Small-footprint SOIC-8 package suitable for replacing bulky transformers or shunt current sensing solutions
- Integrated shield virtually eliminates capacitive coupling from current conductor to die, greatly suppressing output noise due to high dv/dt transients
- Factory-trimmed sensitivity and quiescent output voltage for improved accuracy
- Chopper stabilization results in extremely stable quiescent output voltage



Functional Block Diagram

Package



SO-8

Application

- Variable-frequency
 inverters
- Motor control
- Over-current fault
 protection
- Load detection and management

Description

The CH701 current sensor IC is an economical and precise solution for AC or DC current sensing in industrial, automotive, commercial, and communications systems. The small package is ideal for space-constrained applications while also saving costs due to reduced board area. Typical applications include motor control, load detection and management, switched-mode power supplies, and overcurrent fault protection.

The device consists of a precise, low-offset, linear Hall sensor circuit with a copper conduction path located near the surface of the die. Applied current flowing through this copper conduction path generates a magnetic field which is sensed by the integrated Hall IC and converted into a proportional voltage. A precise, proportional voltage is provided by the low-offset, chopper-stabilized BCD Hall IC,



which is programmed for accuracy after packaging. The output of the device has a positive slope when an increasing current flows through the primary copper conduction path (from pins 1 and 2, to pins 3 and 4), which is the path used for current sensing. The internal resistance of this conductive path is 0.8 m Ω typical, providing low power loss.

The terminals of the conductive path are electrically isolated from the sensor leads (pins 5 through 8). This allows the CH701 current sensor IC to be used in high-side current sense applications without the use of high-side differential amplifiers or other costly isolation techniques.

The CH701 is provided in a small, low-profile surface-mount SOIC8 package. The leadframe is plated with 100% matter tin, which is compatible with standard lead (Pb) free printed circuit board assembly processes. Internally, the device is Pb-free, except for flip-chip high-temperature Pb-based solder balls, currently exempt from RoHS. The device is fully calibrated prior to shipment from the factory.

Similar Products

All products can be operated with 3.3V or 5V supply, and can measure AC and DC.

Product Family	Package	R _{IP}	Bandwidth	Current Range	AEC- Q100 ⁽¹⁾	V _{ISO}	Status
CH703	SOIC-8	1.2mΩ	120kHz	±5A, ±10A, ±20A, ±30A, ±40A, ±50A	NO	2100Vrms	Released (contact factory)
CH701	SOIC-8	1.2mΩ	120kHz	±5A, ±10A, ±20A, ±30A, NO 300 ±40A, ±50A		3000Vrms	Released
CH701W	SO-16W	0.8mΩ	120kHz	±20A, ±30A, ±40A, ±50A, ±60A, ±70A	NO	4800V _{RMS}	Released
CH706	SOIC-8	1.2mΩ	450kHz	±5A, ±10A, ±20A, ±30A, ±40A, ±50A	YES	3000Vrms	Preliminary
CH706W	SO-16W	0.8mΩ	450kHz	±5A, ±10A, ±20A, ±30A, ±40A, ±50A, ±60A, ±70A	YES	4800Vrms	Preliminary
CH707W	SO-16W	0.8mΩ	450kHz	±5A, ±10A, ±20A, ±30A, ±40A, ±50A, ±60A, ±70A	0A, ±30A, 0A, ±50A, YES 4800V _{RMS}		Preliminary
*CH704	CFF-5	0.1mΩ	180kHz	±50A, ±100A, ±150A, ±200A	YES	4800V _{RMS}	Released

*CH704 supply voltage 4.5-5.5V.

(1) AEC-Q100 available.



Revision History

Date	Revision	Change
Nov 2019	1	First draft
May 2021	1.1	Updated format
July 2021	1.2	Added "Similar Products" section
July 2021	1.3	Corrected AU serials zero voltage. Corrected ELin formula.
Aug 2021	1.4	Updated "Similar Products" section
Nov 2021	1.5	Updated product naming convention, add "F" for high-bandwidth version.
Dec 2021	1.6	Updated top-side-marking factory tracking code from 6 characters to 5 characters
Feb 2022	1.7	Updated CH70105**** order information
March 2022	1.8	Removed CH70105AU5*/AU3*/BU5*/BB5*/CU3*/CB3*, CH7010AB3*/CU3*



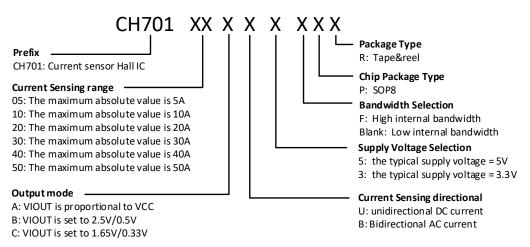
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1 Product Family Members

CH701 is available in a variety of versions. They are distinguished by a specific nomenclature code:



Notes for table 2:

- **CH70105****** available with "low internal bandwidth" version only, and provide by request only; suggest to use CH70110**** as alternatives, or contact factory for newer-gen **CH706**.
- CH701***U* available with degraded temperature drift performance; provide by request only.

Table 1

Part Number	VCC (V)	IPR (A)	Sens (mV/A)	T _j (°C)	Packing
CH70110AB5*	5±0.5	±10	200		
CH70110BB5*	5±0.5	±10	200		
CH70110CB3*	3.3±0.3	±10	132]	
CH70120AB5*	5±0.5	±20	100]	
CH70120AB3*	3.3±0.3	±20	66]	
CH70120BB5*	5±0.5	±20	100]	
CH70120CB3*	3.3±0.3	±20	66	-40 to 150	
CH70130AB5*	5±0.5	±30	66		
CH70130AB3*	3.3±0.3	±30	44		Tape and Reel, 3000
CH70130BB5*	5±0.5	±30	66		
CH70130CB3*	3.3±0.3	±30	44		pieces per reel
CH70140AB5*	5±0.5	±40	50]	
CH70140AB3*	3.3±0.3	±40	33		
CH70140BB5*	5±0.5	±40	50		
CH70140CB3*	3.3±0.3	±40	33	-	
CH70150AB5*	5±0.5	±50	40		
CH70150AB3*	3.3±0.3	±50	26		
CH70150BB5*	5±0.5	±50	40		
CH70150CB3*	3.3±0.3	±50	26		

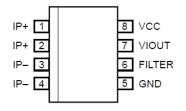
Table 2

Part Number	VCC (V)	IPR (A)	Sens (mV/A)	Tj (°C)	Packing	
CH70105AB5*	5±0.5	±5	400			
CH70105AB3*	3.3±0.3	±5	264			
CH70110AU5*	5±0.5	10	370			
CH70110AU3*	3.3±0.3	10	264			
CH70110BU5*	5±0.5	10	400			
CH70120AU5*	5±0.5	20	200	-40 to 150	-40 to 150	Tape and Reel, 3000
CH70120AU3*	3.3±0.3	20	132			
CH70120BU5*	5±0.5	20	200			
CH70120CU3*	3.3±0.3	20	132		pieces per reel	
CH70130AU5*	5±0.5	30	133	-		
CH70130AU3*	3.3±0.3	30	88			
CH70130BU5*	5±0.5	30	133			
CH70130CU3*	3.3±0.3	30	88			
CH70140AU5*	5±0.5	40	100			
CH70140AU3*	3.3±0.3	40	66			



CH70140BU5*	5±0.5	40	100
CH70140CU3*	3.3±0.3	40	66
CH70150AU5*	5±0.5	50	80
CH70150AU3*	3.3±0.3	50	52
CH70150BU5*	5±0.5	50	80
CH70150CU3*	3.3±0.3	50	52

2 **Pin Definitions and Descriptions**



Package LC, 8-Pin SOICN Pin-Out Diagram

Number	Name	Function
1,2	IP+	Terminals for current being sensed, fused internally
3,4	IP-	Terminals for current being sensed, fused internally
5	GND	Signal ground terminal
6	FILTER	Terminal for external capacitor that sets bandwidth
7	VIOUT	Analog output signal
8	VCC	Device power supply terminal

3 Absolute Maximum Ratings

Parameter	Symbol	Min	Мах	Units
Supply Voltage	V _{cc}	-	6	V
Reverse Supply Voltage	V _{RCC}	-0.1	-	V
Output Voltage	V _{IOUT}	-	V _{CC} +0.5	V
Reverse Output Voltage	V _{RIOUT}	-0.1	-	V
Operating Ambient Temperature	T _A	-40	150	°C
Storage Temperature	Ts	-65	165	°C
Junction temperature	T _{J(max)}		165	°C

Note 1: Exceeding the absolute maximum ratings may cause permanent damage. Exposure to absolute-maximum- rated conditions for extended periods may affect device reliability.

Characteristic Symbol Rating Unit Notes Agency type-tested for 60 seconds per UL 62368-1 (edition Dielectric 3); production-tested at V_ISO for 1 second, in accordance Strength Test Viso 3000 VRMS with UL 62368-1 (edition 3). Voltage UL62368-1 (edition 3) replaces UL60950-1. Working Voltage Maximum approved working voltage for basic (single) V_{pk} or VDC 725 for Basic Vwvbi isolation according to UL 62368-1 (edition 3). 513 Vrms Isolation UL62368-1 (edition 3) replaces UL60950-1.

Isolation Characteristics



Thermal Characteristics

Characteristic	Symbol	Test Conditions*	Value	Units
Package Thermal Resistance (Junction to Ambient)	Reja		23	°C/W
Package Thermal Resistance (Junction to Lead)	Rejl		5	°C/W

4 ESD Protections

Parameter	Value	Unit
All pins 1)	±8000	V
All pins ²⁾	±400	V
All pins ³⁾	±1500	V

1) HBM (human body mode, 100pF, 1.5 k Ω) according to MIL-STD-883H Method 3015.8 2) MM (Machine Mode C=200pF, R=0 Ω) according to JEDEC EIA/JESD22-A115 3) CDM (charged device mode) according to JEDEC EIA/JESD22-C101F



5 **Electrical Characteristics:**

Valid through the full range of T_A , $V_{CC} = 5 V$, $C_F = 0$, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Supply Current	Icc	$V_{CC} = 5 V$, output open	_	10	14	mA
Output Capacitance Load	CL	VIOUT to GND	_	_	10	nF
Output Resistive Load	RL	VIOUT to GND	4.7	_	_	kΩ
Primary Conductor Resistance	R _{IP}	$T_A = 25^{\circ}C$	-	0.8	_	mΩ
Internal Filter Resistance ²	RF(int)		_	1.7	_	kΩ
Rise Time	tr	$I_P = I_P(max), T_A = 25^{\circ}C, C_L = 1 \text{ nF}$	_	3	_	μs
Propagation Delay	tpd	$I_P = I_P(max), T_A = 25^{\circ}C, C_L = 1 \text{ nF}$	_	2	_	μs
Response Time	tresponse	$I_P = I_P(max), T_A = 25^{\circ}C, C_L = 1 \text{ nF}$	-	4	_	μs
Bandwidth	BW	Small signal –3 dB; C _L = 1 nF	_	120	_	kHz
Noise Density	Ind	Input-referenced noise density; $T_A = 25^{\circ}C, C_L = 1 \text{ nF}$	_	150	-	µA ₍ rms)/ √Hz
Noise	In	Input-referenced noise: $C_F = 4.7$ nF, $C_L = 1$ nF, BW = 18 kHz, $T_A = 25^{\circ}C$	_	25	_	mA ₍ rms)
Nonlinearity	Elin	Through full range of I_P		±1		%
Sensitivity Ratiometry Coefficient	SENS_RAT_ COEF	$V_{CC} = 4.5$ to 5.5 V, $T_A = 25^{\circ}C$	_	1.3	_	_
Zero-Current Output Ratiometry Coefficient	QVO_RAT_ COEF	V_{CC} = 4.5 to 5.5 V, T_A = 25°C	_	1	-	_
Octored Vallage 3	Vон	R _L = 4.7 kΩ, TA = 25°C	VCC - 0.2		_	V
Saturation Voltage ³	Vol	R _L = 4.7 kΩ, TA = 25°C	-		0.2	V
Power-On Time	tPO	Output reaches 90% of steady- state level, $T_A = 25^{\circ}C$, $I_P = I_{PR}(max)$ applied	_	62	_	μs
Shorted Output-to-Ground Current	ISC(GND)	T _A = 25°C	-	3.3	_	mA
Shorted Output-to-V _{CC} Current	Isc(vcc)	T _A = 25°C	_	45	_	mA

¹Device may be operated at higher primary current levels, I_P, ambient temperatures, T_A, and internal leadframe temperatures, provided the Maximum Junction Temperature, T_J(max), is not exceeded.

 $^2\mathsf{R}_{\mathsf{F(int)}}$ forms an RC circuit via the FILTER pin.

³The sensor IC will continue to respond to current beyond the range of I_P until the high or low saturation voltage; however, the nonlinearity in this region will be worse than through the rest of the measurement range.



CH70105AB5* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

uniess otherwise spe	Cinica							
Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit		
Nominal Performance								
Supply Voltage	V _{CC}		4.5	-	5.5	V		
Current-Sensing Range	l PR		-5	-	5	A		
Sensitivity	Sens	$I_{PR(min)} < I_{P} < I_{PR(max)}$, VCC = 5V	_	400	_	mV/A		
Zero-Current Output Voltage	V _{IOUT(Q)}	Bidirectional, $I_P = 0 A$, VCC = 5V	_	V _{cc} × 0.5	_	V		
Accuracy Performance	•							
Total Output Error ²	E _{TOT}	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±1	2	%		
Total Output Error Con	nponents ³ E	E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)						
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±1	1.5	%		
Offset Voltage	V _{OE}	$I_P = 0 \text{ A}, T_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±6	10	mV		
Lifetime Drift Characteristics								
Sensitivity Error Lifetime Drift	E sens_drift			±1		%		
Total Output Error Lifetime Drift	E tot_drift			±1		%		



CH70105AB3* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

unicos otherwise spe										
Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit				
Nominal Performance										
Supply Voltage	V _{CC}		3	-	3.6	V				
Current-Sensing Range	l PR		-5	_	5	А				
Sensitivity	Sens	$I_{PR(min)} < I_{P} < I_{PR(max)}$, VCC = 3.3V	_	264	_	mV/A				
Zero-Current Output Voltage	V _{IOUT(Q)}	Bidirectional, $I_P = 0 A$, VCC = 3.3V	_	V _{cc} × 0.5	-	V				
Accuracy Performance	•									
Total Output Error ²	E _{TOT}	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±1	2	%				
Total Output Error Con	nponents ³ E	E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)								
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±1	1.5	%				
Offset Voltage	V _{OE}	$I_P = 0 \text{ A}, T_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±6	10	mV				
Lifetime Drift Characte	ristics									
Sensitivity Error Lifetime Drift	E sens_drift			±1		%				
Total Output Error Lifetime Drift	E tot_drift			±1		%				



CH70110AU5* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

uniess otherwise spe									
Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit			
Nominal Performance									
Supply Voltage	V _{CC}		4.5	-	5.5	V			
Current-Sensing Range	l PR		0	_	10	А			
Sensitivity	Sens	$I_{PR(min)} < I_{P} < I_{PR(max)}$, VCC = 5V	_	370	_	mV/A			
Zero-Current Output Voltage	V _{IOUT(Q)}	Unidirectional, $I_P = 0 A$, VCC = 5V	_	0.65	_	V			
Accuracy Performance	•								
Total Output Error ²	E _{TOT}	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-2.5	±1.5	2.5	%			
Total Output Error Con	nponents ³ I	E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)							
Sensitivity Error	Esens	$I_{P} = I_{PR(max)}, T_{j} = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±1	2	%			
Offset Voltage	V _{OE}	$I_P = 0 \text{ A}, T_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-15	±7	15	mV			
Lifetime Drift Characte	ristics								
Sensitivity Error Lifetime Drift	E sens_drift			±1		%			
Total Output Error Lifetime Drift	E _{tot_drift}			±1		%			



CH70110AU3* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit			
Nominal Performance									
Supply Voltage	V _{cc}		3	_	3.6	V			
Current-Sensing Range	I PR		0	-	10	А			
Sensitivity	Sens	$ _{PR(min)} < _{P} < _{PR(max)}$, VCC = 3.3V	-	240	-	mV/A			
Zero-Current Output Voltage	V _{IOUT(Q)}	Unidirectional, $I_P = 0 A$, VCC = 3.3V	-	0.45	-	V			
Accuracy Performance	9								
Total Output Error ²	E _{TOT}	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-2.5	±1.5	2.5	%			
Total Output Error Co		E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)							
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±1	2	%			
Offset Voltage	V _{OE}	I _P = 0 A, T _j =-40°C to 150°C	-15	±7	15	mV			
Lifetime Drift Characte	eristics								
Sensitivity Error Lifetime Drift	Edrift			±1		%			
Total Output Error Lifetime Drift	E _{tot_drift}			±1		%			



CH70110AB5* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit				
Nominal Performance										
Supply Voltage	V _{CC}		4.5	-	5.5	V				
Current-Sensing Range	l PR		-10	_	10	A				
Sensitivity	Sens	$I_{PR(min)} < I_{P} < I_{PR(max)}$, VCC = 5V	_	200	_	mV/A				
Zero-Current Output Voltage	V _{IOUT(Q)}	Bidirectional, $I_P = 0 A$, VCC = 5V	_	V _{cc} × 0.5	-	V				
Accuracy Performance	9									
Total Output Error ²	E _{TOT}	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±1	2	%				
Total Output Error Cor	nponents ³ E	E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)								
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±1	1.5	%				
Offset Voltage	V _{OE}	$I_P = 0 \text{ A}, T_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±6	10	mV				
Lifetime Drift Characte	ristics									
Sensitivity Error Lifetime Drift	Edrift			±1		%				
Total Output Error Lifetime Drift	E _{tot_drift}			±1		%				



CH70110BU5* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

iness otherwise specified								
Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit		
Nominal Performance								
Supply Voltage	V _{CC}		4.5	-	5.5	V		
Current-Sensing Range	l PR		0	-	10	А		
Sensitivity	Sens	$I_{PR(min)} < I_{P} < I_{PR(max)}$	_	370	_	mV/A		
Zero-Current Output Voltage	V _{IOUT(Q)}	Unidirectional, I _P = 0 A	_	0.65	_	V		
Accuracy Performance	•							
Total Output Error ²	E _{TOT}	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-2.5	±1.5	2.5	%		
Total Output Error Con	nponents ³ E	Tot = E _{SENS} + 100 × V _{OE} /(Sens × I _P)						
Sensitivity Error	Esens	$I_{P} = I_{PR(max)}, T_{j} = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±1	2	%		
Offset Voltage	V _{OE}	$I_P = 0 \text{ A}, T_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-15	±7	15	mV		
Lifetime Drift Characte	ristics							
Sensitivity Error Lifetime Drift	E sens_drift			±1		%		
Total Output Error Lifetime Drift	E _{tot_drift}			±1		%		



CH70110BB5* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

uniess otherwise spe									
Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit			
Nominal Performance									
Supply Voltage	V _{CC}		4.5	-	5.5	V			
Current-Sensing Range	l PR		-10	-	10	А			
Sensitivity	Sens	$ _{PR(min)} < _{P} < _{PR(max)}$	_	200	_	mV/A			
Zero-Current Output Voltage	V _{IOUT(Q)}	Bidirectional, $I_P = 0 A$	_	2.5	_	V			
Accuracy Performance	9								
Total Output Error ²	E _{TOT}	$I_{P} = I_{PR(max)}, T_{j} = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±1	2	%			
Total Output Error Cor	nponents ³ E	E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)							
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±1	1.5	%			
Offset Voltage	V _{OE}	$I_P = 0 \text{ A}, T_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±6	10	mV			
Lifetime Drift Characte	ristics								
Sensitivity Error Lifetime Drift	E sens_drift			±1		%			
Total Output Error Lifetime Drift	E tot_drift			±1		%			



CH70110CB5* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

uniess otherwise spe	Joinea								
Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit			
Nominal Performance									
Supply Voltage	V _{CC}		4.5	-	5.5	V			
Current-Sensing Range	l PR		-10	-	10	А			
Sensitivity	Sens	$ _{PR(min)} < _{P} < _{PR(max)}$	_	132	_	mV/A			
Zero-Current Output Voltage	V _{IOUT(Q)}	Bidirectional, $I_P = 0 A$	_	1.65	_	V			
Accuracy Performance	9								
Total Output Error ²	E _{TOT}	$I_{P} = I_{PR(max)}, T_{j} = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±1	2	%			
Total Output Error Cor	nponents ³	E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)							
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±1	1.5	%			
Offset Voltage	V _{OE}	$I_P = 0 \text{ A}, T_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±6	10	mV			
Lifetime Drift Characte	ristics								
Sensitivity Error Lifetime Drift	E sens_drift			±1		%			
Total Output Error Lifetime Drift	E tot_drift			±1		%			



CH70110CB3* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit			
Nominal Performance									
Supply Voltage	V _{cc}		3	_	3.6	V			
Current-Sensing Range	l PR		-10	_	10	A			
Sensitivity	Sens	$ _{PR(min)} < _{P} < _{PR(max)}$	_	132	-	mV/A			
Zero-Current Output Voltage	V _{IOUT(Q)}	Bidirectional, I _P = 0 A	_	1.65	_	V			
Accuracy Performance	9								
Total Output Error ²	E _{TOT}	$I_{P} = I_{PR(max)}, T_{j} = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±1	2	%			
Total Output Error Cor		E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)							
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±1	1.5	%			
Offset Voltage	V _{OE}	$I_{P} = 0 \text{ A}, T_{j} = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±6	10	mV			
Lifetime Drift Characte	ristics								
Sensitivity Error Lifetime Drift	Edrift			±1		%			
Total Output Error Lifetime Drift	E _{tot_drift}			±1		%			



CH70120AU5* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit			
Nominal Performance									
Supply Voltage	V _{CC}		4.5	_	5.5	V			
Current-Sensing Range	l PR		0	-	20	A			
Sensitivity	Sens	$I_{PR(min)} < I_{P} < I_{PR(max)}$, VCC = 5V	-	200	-	mV/A			
Zero-Current Output Voltage	V _{IOUT(Q)}	Unidirectional, $I_P = 0 A$, VCC = 5V	_	V _{cc} × 0.1	-	V			
Accuracy Performance	9								
Total Output Error ²	E _{TOT}	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±0.7	2	%			
Total Output Error Cor	nponents ³	E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)							
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±0.7	1.5	%			
Offset Voltage	V _{OE}	$I_P = 0 \text{ A}, T_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±6	10	mV			
Lifetime Drift Characte	ristics								
Sensitivity Error Lifetime Drift	Edrift			±1		%			
Total Output Error Lifetime Drift	E tot_drift			±1		%			



CH70120AU3* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Typ.1	Max.	Unit			
Nominal Performance									
Supply Voltage	V _{CC}		3	_	3.6	V			
Current-Sensing Range	I PR		0	_	20	A			
Sensitivity	Sens	$ _{PR(min)} < _{P} < _{PR(max)}$, VCC = 3.3V	-	132	-	mV/A			
Zero-Current Output Voltage	V _{IOUT(Q)}	Unidirectional, $I_P = 0 \text{ A}$, VCC = 3.3V	-	0.45	Ι	V			
Accuracy Performance	e								
Total Output Error ²	E _{TOT}	$I_{P} = I_{PR(max)}, T_{j} = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±0.7	2	%			
Total Output Error Cor	nponents ³	E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)							
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±0.7	1.5	%			
Offset Voltage	V _{OE}	I _P = 0 A, T _j = -40°C to 150°C	-10	±6	10	mV			
Lifetime Drift Characte	eristics								
Sensitivity Error Lifetime Drift	Edrift			±1		%			
Total Output Error Lifetime Drift	E tot_drift			±1		%			



CH70120AB5* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

uniess otherwise spe								
Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit		
Nominal Performance								
Supply Voltage	V _{CC}		4.5	-	5.5	V		
Current-Sensing Range	l PR		-20	-	20	А		
Sensitivity	Sens	$I_{PR(min)} < I_{P} < I_{PR(max)}$, VCC = 5V	-	100	-	mV/A		
Zero-Current Output Voltage	V _{IOUT(Q)}	Bidirectional, $I_P = 0 A$, VCC = 5V	_	V _{CC} × 0.5	-	V		
Accuracy Performance	9							
Total Output Error ²	E _{TOT}	$I_{P} = I_{PR(max)}, T_{j} = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±0.8	2	%		
Total Output Error Cor	nponents ³ I	E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)						
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±0.6	1.5	%		
Offset Voltage	V _{OE}	$I_P = 0 \text{ A}, T_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±5	10	mV		
Lifetime Drift Characte	ristics							
Sensitivity Error Lifetime Drift	E sens_drift			±1		%		
Total Output Error Lifetime Drift	E tot_drift			±1		%		



CH70120AB3* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

uniess otherwise spe	uniess otherwise specified									
Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit				
Nominal Performance										
Supply Voltage	V _{cc}		3	-	3.6	V				
Current-Sensing Range	l PR		-20	-	20	А				
Sensitivity	Sens	$ _{PR(min)} < _{P} < _{PR(max)}$, VCC = 3.3V	-	66	-	mV/A				
Zero-Current Output Voltage	V _{IOUT(Q)}	Bidirectional, $I_P = 0 A$, VCC = 3.3V	_	V _{CC} × 0.5	-	V				
Accuracy Performance	•									
Total Output Error ²	E _{TOT}	$I_{P} = I_{PR(max)}, T_{j} = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±0.8	2	%				
Total Output Error Con	nponents ³ I	E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)								
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±0.6	1.5	%				
Offset Voltage	V _{OE}	$I_{P} = 0 \text{ A}, T_{j} = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±5	10	mV				
Lifetime Drift Characte	ristics									
Sensitivity Error Lifetime Drift	E sens_drift			±1		%				
Total Output Error Lifetime Drift	Etot_drift			±1		%				



CH70120BU5* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit			
Nominal Performance									
Supply Voltage	V _{cc}		4.5	_	5.5	V			
Current-Sensing Range	l PR		0	_	20	A			
Sensitivity	Sens	$ _{PR(min)} < _{P} < _{PR(max)}$	-	200	-	mV/A			
Zero-Current Output Voltage	V _{IOUT(Q)}	Unidirectional, I _P = 0 A	_	0.5	_	V			
Accuracy Performance	•								
Total Output Error ²	E _{TOT}	$I_{P} = I_{PR(max)}, T_{j} = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±0.7	2	%			
Total Output Error Cor		E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)							
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±0.7	1.5	%			
Offset Voltage	V _{OE}	$I_{P} = 0 \text{ A}, T_{j} = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±6	10	mV			
Lifetime Drift Characte	ristics								
Sensitivity Error Lifetime Drift	Edrift			±1		%			
Total Output Error Lifetime Drift	E tot_drift			±1		%			



CH70120BB5* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

uniess otherwise specified									
Characteristic	Symbol	Test Conditions	Min.	Typ.1	Max.	Unit			
Nominal Performance									
Supply Voltage	V _{cc}		4.5	-	5.5	V			
Current-Sensing Range	l PR		-20	Ι	20	А			
Sensitivity	Sens	$I_{PR(min)} < I_{P} < I_{PR(max)}$	_	100	_	mV/A			
Zero-Current Output Voltage	V _{IOUT(Q)}	Bidirectional, $I_P = 0 A$	_	2.5	-	V			
Accuracy Performance	•								
Total Output Error ²	E _{TOT}	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±0.8	2	%			
Total Output Error Con	nponents ³ I	E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)							
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±0.6	1.5	%			
Offset Voltage	V _{OE}	$I_P = 0 \text{ A}, T_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±5	10	mV			
Lifetime Drift Characte	ristics								
Sensitivity Error Lifetime Drift	E sens_drift			±1		%			
Total Output Error Lifetime Drift	E tot_drift			±1		%			



CH70120CU5* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

Characteristic		Test Conditions	N.C.	T 1	Max	11			
Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit			
Nominal Performance									
Supply Voltage	V _{CC}		4.5	-	5.5	V			
Current-Sensing Range	l PR		0	-	20	А			
Sensitivity	Sens	$I_{PR(min)} < I_{P} < I_{PR(max)}$	_	132	_	mV/A			
Zero-Current Output Voltage	V _{IOUT(Q)}	Unidirectional, I _P = 0 A	_	0.33	_	V			
Accuracy Performance	•								
Total Output Error ²	E _{TOT}	$I_{P} = I_{PR(max)}, T_{j} = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±0.7	2	%			
Total Output Error Cor	nponents ³ I	$E_{TOT} = E_{SENS} + 100 \times V_{OE}/(Sens \times I_P)$							
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±0.7	1.5	%			
Offset Voltage	V _{OE}	$I_P = 0 \text{ A}, \text{T}_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±6	10	mV			
Lifetime Drift Characte	ristics								
Sensitivity Error Lifetime Drift	E sens_drift			±1		%			
Total Output Error Lifetime Drift	E tot_drift			±1		%			



CH70120CU3* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

uniess otherwise specified									
Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit			
Nominal Performance									
Supply Voltage	V _{CC}		3	-	3.6	V			
Current-Sensing Range	l PR		0	-	20	А			
Sensitivity	Sens	$ _{PR(min)} < _{P} < _{PR(max)}$	_	132	_	mV/A			
Zero-Current Output Voltage	V _{IOUT(Q)}	Unidirectional, I _P = 0 A	_	0.33	Ι	V			
Accuracy Performance	9								
Total Output Error ²	E _{TOT}	$I_{P} = I_{PR(max)}, T_{j} = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±0.7	2	%			
Total Output Error Con	nponents ³	E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)							
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±0.7	1.5	%			
Offset Voltage	V _{OE}	$I_P = 0 \text{ A}, T_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±6	10	mV			
Lifetime Drift Characte	ristics								
Sensitivity Error Lifetime Drift	Edrift			±1		%			
Total Output Error Lifetime Drift	E tot_drift			±1		%			



CH70120CB5* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

uniess otherwise specified									
Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit			
Nominal Performance									
Supply Voltage	V _{cc}		4.5	-	5.5	V			
Current-Sensing Range	l PR		-20	_	20	А			
Sensitivity	Sens	$I_{PR(min)} < I_{P} < I_{PR(max)}$	_	66	-	mV/A			
Zero-Current Output Voltage	V _{IOUT(Q)}	Bidirectional, $I_P = 0 A$	_	1.65	_	V			
Accuracy Performance	•								
Total Output Error ²	E _{TOT}	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±0.8	2	%			
Total Output Error Con	nponents ³ I	E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)							
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±0.6	1.5	%			
Offset Voltage	V _{OE}	$I_P = 0 \text{ A}, T_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±5	10	mV			
Lifetime Drift Characte	ristics								
Sensitivity Error Lifetime Drift	E sens_drift			±1		%			
Total Output Error Lifetime Drift	E tot_drift			±1		%			



CH70120CB3* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

unicos otherwise spe	uniess otherwise specified									
Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit				
Nominal Performance										
Supply Voltage	V _{CC}		3	-	3.6	V				
Current-Sensing Range	l PR		-20	-	20	А				
Sensitivity	Sens	$I_{PR(min)} < I_{P} < I_{PR(max)}$	_	66	_	mV/A				
Zero-Current Output Voltage	V _{IOUT(Q)}	Bidirectional, $I_P = 0 A$	_	1.65	_	V				
Accuracy Performance	9									
Total Output Error ²	E _{TOT}	$I_{P} = I_{PR(max)}, T_{j} = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±0.8	2	%				
Total Output Error Con	nponents ³	E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)								
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±0.6	1.5	%				
Offset Voltage	V _{OE}	$I_P = 0 \text{ A}, T_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±5	10	mV				
Lifetime Drift Characte	ristics									
Sensitivity Error Lifetime Drift	Edrift			±1		%				
Total Output Error Lifetime Drift	E tot_drift			±1		%				



CH70130AU5* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

unless otherwise spe									
Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit			
Nominal Performance									
Supply Voltage	V _{CC}		4.5	-	5.5	V			
Current-Sensing Range	l PR		0	_	30	А			
Sensitivity	Sens	$I_{PR(min)} < I_{P} < I_{PR(max)}$, VCC = 5V	-	133	_	mV/A			
Zero-Current Output Voltage	V _{IOUT(Q)}	Unidirectional, $I_P = 0 A$, VCC = 5V	_	V _{cc} × 0.1	Ι	V			
Accuracy Performance	e								
Total Output Error ²	E _{TOT}	$I_{P} = I_{PR(max)}, T_{j} = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±0.7	2	%			
Total Output Error Cor	nponents ³	E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)							
Sensitivity Error	E _{sens}	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±0.7	1.5	%			
Offset Voltage	V _{OE}	$I_P = 0 \text{ A}, T_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±6	10	mV			
Lifetime Drift Characte	eristics								
Sensitivity Error Lifetime Drift	Edrift			±1		%			
Total Output Error Lifetime Drift	E tot_drift			±1		%			



CH70130AU3* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

unless otherwise spe	onica								
Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit			
Nominal Performance									
Supply Voltage	V _{CC}		3	-	3.6	V			
Current-Sensing Range	l PR		0	-	30	А			
Sensitivity	Sens	$I_{PR(min)} < I_{P} < I_{PR(max)}$, VCC = 3.3V	-	88	-	mV/A			
Zero-Current Output Voltage	V _{IOUT(Q)}	Unidirectional, $I_P = 0 A$, VCC = 3.3V	_	0.45	-	V			
Accuracy Performance	•								
Total Output Error ²	E _{TOT}	$I_{P} = I_{PR(max)}, T_{j} = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±0.7	2	%			
Total Output Error Con	nponents ³ I	E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)							
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±0.7	1.5	%			
Offset Voltage	V _{OE}	$I_{P} = 0 \text{ A}, T_{j} = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±6	10	mV			
Lifetime Drift Characte	ristics								
Sensitivity Error Lifetime Drift	E sens_drift			±1		%			
Total Output Error Lifetime Drift	Etot_drift			±1		%			



CH70130AB5* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

uniess otherwise spe									
Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit			
Nominal Performance									
Supply Voltage	V _{cc}		4.5	-	5.5	V			
Current-Sensing Range	l PR		-30	-	30	А			
Sensitivity	Sens	$ _{PR(min)} < _{P} < _{PR(max)}$, VCC = 5V	-	66	-	mV/A			
Zero-Current Output Voltage	V _{IOUT(Q)}	Bidirectional, $I_P = 0 A$, VCC = 5V	_	V _{CC} × 0.5	-	V			
Accuracy Performance	9								
Total Output Error ²	E _{TOT}	$I_{P} = I_{PR(max)}, T_{j} = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±0.8	2	%			
Total Output Error Cor	nponents ³ I	E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)							
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±0.8	1.5	%			
Offset Voltage	V _{OE}	$I_P = 0 \text{ A}, T_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±6	10	mV			
Lifetime Drift Characte	ristics								
Sensitivity Error Lifetime Drift	E sens_drift			±1		%			
Total Output Error Lifetime Drift	E tot_drift			±1		%			



CH70130AB3* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

uniess otherwise spe									
Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit			
Nominal Performance									
Supply Voltage	V _{CC}		3	-	3.6	V			
Current-Sensing Range	l PR		-30	-	30	А			
Sensitivity	Sens	$I_{PR(min)} < I_{P} < I_{PR(max)}$, VCC = 3.3V	_	44	_	mV/A			
Zero-Current Output Voltage	V _{IOUT(Q)}	Bidirectional, $I_P = 0 A$, VCC = 3.3V	_	V _{CC} × 0.5	Ι	V			
Accuracy Performance	e								
Total Output Error ²	E _{TOT}	$I_{P} = I_{PR(max)}, T_{j} = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±0.8	2	%			
Total Output Error Cor	nponents ³	E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)							
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±0.8	1.5	%			
Offset Voltage	V _{OE}	$I_P = 0 \text{ A}, T_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±6	10	mV			
Lifetime Drift Characte	eristics								
Sensitivity Error Lifetime Drift	Edrift			±1		%			
Total Output Error Lifetime Drift	E tot_drift			±1		%			



CH70130BU5* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

unicos otnerwise spe	uniess otherwise specified									
Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit				
Nominal Performance										
Supply Voltage	V _{CC}		4.5	-	5.5	V				
Current-Sensing Range	l PR		0	-	30	А				
Sensitivity	Sens	$I_{PR(min)} < I_{P} < I_{PR(max)}$	_	133	_	mV/A				
Zero-Current Output Voltage	V _{IOUT(Q)}	Unidirectional, I _P = 0 A	_	0.5	_	V				
Accuracy Performance	•									
Total Output Error ²	E _{TOT}	$I_{P} = I_{PR(max)}, T_{j} = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±0.7	2	%				
Total Output Error Con	nponents ³	E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)								
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±0.7	1.5	%				
Offset Voltage	V _{OE}	$I_P = 0 \text{ A}, T_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±6	10	mV				
Lifetime Drift Characte	ristics									
Sensitivity Error Lifetime Drift	E sens_drift			±1		%				
Total Output Error Lifetime Drift	E tot_drift			±1		%				



CH70130BB5* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

uniess otherwise specified									
Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit			
Nominal Performance									
Supply Voltage	V _{CC}		4.5	-	5.5	V			
Current-Sensing Range	l PR		-30	-	30	А			
Sensitivity	Sens	$I_{PR(min)} < I_{P} < I_{PR(max)}$	_	66	_	mV/A			
Zero-Current Output Voltage	V _{IOUT(Q)}	Bidirectional, $I_P = 0 A$	_	2.5	_	V			
Accuracy Performance	•								
Total Output Error ²	E _{TOT}	$I_{P} = I_{PR(max)}, T_{j} = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±0.8	2	%			
Total Output Error Con	nponents ³	E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)							
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±0.6	1.5	%			
Offset Voltage	V _{OE}	$I_P = 0 \text{ A}, T_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±5	10	mV			
Lifetime Drift Characte	ristics								
Sensitivity Error Lifetime Drift	E sens_drift			±1		%			
Total Output Error Lifetime Drift	E tot_drift			±1		%			



CH70130CU5* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

uniess otherwise spe				— 1				
Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit		
Nominal Performance								
Supply Voltage	V _{cc}		4.5	Ι	5.5	V		
Current-Sensing Range	l PR		0	Ι	30	А		
Sensitivity	Sens	$I_{PR(min)} < I_{P} < I_{PR(max)}$	_	88	-	mV/A		
Zero-Current Output Voltage	V IOUT(Q)	Unidirectional, I _P = 0 A	_	0.33	_	V		
Accuracy Performance								
Total Output Error ²	E _{TOT}	$I_{P} = I_{PR(max)}, T_{j} = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±0.7	2	%		
Total Output Error Components ³ E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)								
Sensitivity Error	Esens	$I_P = I_{PR(max)}$, $T_j = -40^{\circ}C$ to $150^{\circ}C$	-1.5	±0.7	1.5	%		
Offset Voltage	V _{OE}	$I_P = 0 \text{ A}, T_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±6	10	mV		
Lifetime Drift Characteristics								
Sensitivity Error Lifetime Drift	E sens_drift			±1		%		
Total Output Error Lifetime Drift	Etot_drift			±1		%		



CH70130CU3* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

unless otherwise spe	, cinica							
Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit		
Nominal Performance								
Supply Voltage	V _{CC}		3	-	3.6	V		
Current-Sensing Range	l PR		0	-	30	А		
Sensitivity	Sens	$I_{PR(min)} < I_{P} < I_{PR(max)}$	_	88	_	mV/A		
Zero-Current Output Voltage	V _{IOUT(Q)}	Unidirectional, I _P = 0 A	_	0.33	_	V		
Accuracy Performance								
Total Output Error ²	E _{TOT}	$I_{P} = I_{PR(max)}, T_{j} = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±0.7	2	%		
Total Output Error Components ³ E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)								
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±0.7	1.5	%		
Offset Voltage	V _{OE}	$I_P = 0 \text{ A}, T_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±6	10	mV		
Lifetime Drift Characteristics								
Sensitivity Error Lifetime Drift	Edrift			±1		%		
Total Output Error Lifetime Drift	E tot_drift			±1		%		



CH70130CB5* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

uniess otherwise spe	cineu						
Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit	
Nominal Performance							
Supply Voltage	V _{cc}		4.5	-	5.5	V	
Current-Sensing Range	l PR		-30	_	30	А	
Sensitivity	Sens	$I_{PR(min)} < I_{P} < I_{PR(max)}$	-	44	_	mV/A	
Zero-Current Output Voltage	V _{IOUT(Q)}	Bidirectional, $I_P = 0 A$	_	1.65	_	V	
Accuracy Performance							
Total Output Error ²	E _{TOT}	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±0.8	2	%	
Total Output Error Components ³ E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)							
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±0.6	1.5	%	
Offset Voltage	V _{OE}	$I_P = 0 \text{ A}, T_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±5	10	mV	
Lifetime Drift Characteristics							
Sensitivity Error Lifetime Drift	E sens_drift			±1		%	
Total Output Error Lifetime Drift	E tot_drift			±1		%	



CH70130CB3* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

uniess otherwise spe										
Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit				
Nominal Performance										
Supply Voltage	V _{CC}		3	-	3.6	V				
Current-Sensing Range	l PR		-30	-	30	А				
Sensitivity	Sens	$ _{PR(min)} < _{P} < _{PR(max)}$	_	44	-	mV/A				
Zero-Current Output Voltage	V _{IOUT(Q)}	Bidirectional, $I_P = 0 A$	_	1.65	_	V				
Accuracy Performance	9									
Total Output Error ²	E _{TOT}	$I_{P} = I_{PR(max)}, T_{j} = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±0.8	2	%				
Total Output Error Cor	nponents ³ I	E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)								
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±0.6	1.5	%				
Offset Voltage	V _{OE}	$I_P = 0 \text{ A}, T_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±5	10	mV				
Lifetime Drift Characte	ristics									
Sensitivity Error Lifetime Drift	E sens_drift			±1		%				
Total Output Error Lifetime Drift	E tot_drift			±1		%				



CH70140AU5* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit				
Nominal Performance										
Supply Voltage	V _{CC}		4.5	-	5.5	V				
Current-Sensing Range	l PR		0	-	40	А				
Sensitivity	Sens	$I_{PR(min)} < I_{P} < I_{PR(max)}$, VCC = 5V	-	100	_	mV/A				
Zero-Current Output Voltage	V _{IOUT(Q)}	Unidirectional, $I_P = 0 A$, VCC = 5V	_	V _{CC} × 0.1	_	V				
Accuracy Performance	•									
Total Output Error ²	E _{TOT}	$I_{P} = I_{PR(max)}, T_{j} = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±0.7	2	%				
Total Output Error Cor	nponents ³	E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)								
Sensitivity Error	Esens	$I_P = I_{PR(max)}$, $T_j = -40^{\circ}C$ to $150^{\circ}C$	-1.5	±0.7	1.5	%				
Offset Voltage	V _{OE}	$I_P = 0 \text{ A}, T_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±6	10	mV				
Lifetime Drift Characte	ristics									
Sensitivity Error Lifetime Drift	E sens_drift			±1		%				
Total Output Error Lifetime Drift	E tot_drift			±1		%				



CH70140AU3* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

uniess otherwise specified									
Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit			
Nominal Performance									
Supply Voltage	V _{CC}		3	-	3.6	V			
Current-Sensing Range	l PR		0	-	40	А			
Sensitivity	Sens	$I_{PR(min)} < I_{P} < I_{PR(max)}$, VCC = 3.3V	_	66	_	mV/A			
Zero-Current Output Voltage	V _{IOUT(Q)}	Unidirectional, $I_P = 0 A$, VCC = 3.3V	_	0.45	-	V			
Accuracy Performance	9								
Total Output Error ²	E _{TOT}	$I_{P} = I_{PR(max)}, T_{j} = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±0.7	2	%			
Total Output Error Con	nponents ³ I	E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)							
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±0.7	1.5	%			
Offset Voltage	V _{OE}	$I_P = 0 \text{ A}, T_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±6	10	mV			
Lifetime Drift Characte	ristics								
Sensitivity Error Lifetime Drift	E sens_drift			±1		%			
Total Output Error Lifetime Drift	E tot_drift			±1		%			



CH70140AB5* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

uniess otherwise spe									
Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit			
Nominal Performance									
Supply Voltage	V _{CC}		4.5	-	5.5	V			
Current-Sensing Range	l PR		-40	-	40	А			
Sensitivity	Sens	$I_{PR(min)} < I_{P} < I_{PR(max)}$, VCC = 5V	_	50	_	mV/A			
Zero-Current Output Voltage	V _{IOUT(Q)}	Bidirectional, $I_P = 0 A$, VCC = 5V	_	V _{CC} × 0.5	_	V			
Accuracy Performance	e								
Total Output Error ²	E _{TOT}	$I_{P} = I_{PR(max)}, T_{j} = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±0.8	2	%			
Total Output Error Cor	nponents ³	E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)							
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±0.6	1.5	%			
Offset Voltage	V _{OE}	$I_P = 0 \text{ A}, T_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±5	10	mV			
Lifetime Drift Characte	eristics								
Sensitivity Error Lifetime Drift	Edrift			±1		%			
Total Output Error Lifetime Drift	E tot_drift			±1		%			



CH70140AB3* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit				
Nominal Performance										
Supply Voltage	V _{CC}		3	-	3.6	V				
Current-Sensing Range	l PR		-40	Ι	40	А				
Sensitivity	Sens	$I_{PR(min)} < I_{P} < I_{PR(max)}$, VCC = 3.3V	_	33	_	mV/A				
Zero-Current Output Voltage	V _{IOUT(Q)}	Bidirectional, $I_P = 0 A$, VCC = 3.3V	_	V _{CC} × 0.5	_	V				
Accuracy Performance	9									
Total Output Error ²	E _{TOT}	$I_{P} = I_{PR(max)}, T_{j} = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±0.8	2	%				
Total Output Error Cor	nponents ³	$E_{TOT} = E_{SENS} + 100 \times V_{OE}/(Sens \times I_P)$								
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±0.6	1.5	%				
Offset Voltage	V _{OE}	$I_P = 0 \text{ A}, T_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±5	10	mV				
Lifetime Drift Characte	ristics									
Sensitivity Error Lifetime Drift	Edrift			±1		%				
Total Output Error Lifetime Drift	E tot_drift			±1		%				



CH70140BU5* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

unicos otnerwise spe	uniess otherwise specified									
Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit				
Nominal Performance										
Supply Voltage	V _{CC}		4.5	-	5.5	V				
Current-Sensing Range	l PR		0	-	40	А				
Sensitivity	Sens	$I_{PR(min)} < I_{P} < I_{PR(max)}$	_	100	_	mV/A				
Zero-Current Output Voltage	V _{IOUT(Q)}	Unidirectional, I _P = 0 A	_	0.5	_	V				
Accuracy Performance	•									
Total Output Error ²	E _{TOT}	$I_{P} = I_{PR(max)}, T_{j} = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±0.7	2	%				
Total Output Error Con	nponents ³	E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)								
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±0.7	1.5	%				
Offset Voltage	V _{OE}	$I_P = 0 \text{ A}, T_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±6	10	mV				
Lifetime Drift Characte	ristics									
Sensitivity Error Lifetime Drift	E sens_drift			±1		%				
Total Output Error Lifetime Drift	E tot_drift			±1		%				



CH70140BB5* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

uniess otherwise specified									
Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit			
Nominal Performance									
Supply Voltage	V _{cc}		4.5	-	5.5	V			
Current-Sensing Range	l PR		-40	_	40	А			
Sensitivity	Sens	$I_{PR(min)} < I_{P} < I_{PR(max)}$	-	50	-	mV/A			
Zero-Current Output Voltage	V _{IOUT(Q)}	Bidirectional, $I_P = 0 A$	_	2.5	_	V			
Accuracy Performance	•								
Total Output Error ²	E _{TOT}	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±0.8	2	%			
Total Output Error Cor	nponents ³ I	E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)							
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±0.6	1.5	%			
Offset Voltage	V _{OE}	$I_P = 0 \text{ A}, T_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±5	10	mV			
Lifetime Drift Characte	ristics								
Sensitivity Error Lifetime Drift	E sens_drift			±1		%			
Total Output Error Lifetime Drift	E tot_drift			±1		%			



CH70140CU5* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

unicos otnerwise spe	uniess otherwise specified									
Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit				
Nominal Performance										
Supply Voltage	V _{CC}		4.5	-	5.5	V				
Current-Sensing Range	l PR		0	-	40	А				
Sensitivity	Sens	$I_{PR(min)} < I_{P} < I_{PR(max)}$	_	66	_	mV/A				
Zero-Current Output Voltage	V _{IOUT(Q)}	Unidirectional, I _P = 0 A	_	0.33	_	V				
Accuracy Performance	•									
Total Output Error ²	E _{TOT}	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±0.7	2	%				
Total Output Error Con	nponents ³	E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)								
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±0.7	1.5	%				
Offset Voltage	V _{OE}	$I_P = 0 \text{ A}, T_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±6	10	mV				
Lifetime Drift Characte	ristics									
Sensitivity Error Lifetime Drift	E sens_drift			±1		%				
Total Output Error Lifetime Drift	E tot_drift			±1		%				



CH70140CU3* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

uniess otherwise spe	uniess otherwise specified									
Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit				
Nominal Performance										
Supply Voltage	V _{cc}		3	-	3.6	V				
Current-Sensing Range	l PR		0	-	40	А				
Sensitivity	Sens	$I_{PR(min)} < I_{P} < I_{PR(max)}$	-	66	_	mV/A				
Zero-Current Output Voltage	V _{IOUT(Q)}	Unidirectional, I _P = 0 A	_	0.33	_	V				
Accuracy Performance	•									
Total Output Error ²	E _{TOT}	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±0.7	2	%				
Total Output Error Con	nponents ³ I	E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)								
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±0.7	1.5	%				
Offset Voltage	V _{OE}	$I_P = 0 \text{ A}, T_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±6	10	mV				
Lifetime Drift Characte	ristics									
Sensitivity Error Lifetime Drift	E sens_drift			±1		%				
Total Output Error Lifetime Drift	E tot_drift			±1		%				



CH70140CB5* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

unicos otnerwise spe	uniess otherwise specified									
Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit				
Nominal Performance										
Supply Voltage	V _{CC}		4.5	-	5.5	V				
Current-Sensing Range	l PR		-40	-	40	А				
Sensitivity	Sens	$ _{PR(min)} < _{P} < _{PR(max)}$	_	33	_	mV/A				
Zero-Current Output Voltage	V _{IOUT(Q)}	Bidirectional, $I_P = 0 A$	_	1.65	_	V				
Accuracy Performance	•									
Total Output Error ²	E _{TOT}	$I_{P} = I_{PR(max)}, T_{j} = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±0.8	2	%				
Total Output Error Con	nponents ³	E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)								
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±0.6	1.5	%				
Offset Voltage	V _{OE}	$I_{P} = 0 \text{ A}, T_{j} = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±5	10	mV				
Lifetime Drift Characte	ristics									
Sensitivity Error Lifetime Drift	E sens_drift			±1		%				
Total Output Error Lifetime Drift	E tot_drift			±1		%				



CH70140CB3* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

uniess otherwise spe								
Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit		
Nominal Performance								
Supply Voltage	V _{CC}		3	-	3.6	V		
Current-Sensing Range	l PR		-40	-	40	А		
Sensitivity	Sens	$ _{PR(min)} < _{P} < _{PR(max)}$	_	33	_	mV/A		
Zero-Current Output Voltage	V _{IOUT(Q)}	Bidirectional, $I_P = 0 A$	_	1.65	_	V		
Accuracy Performance	9							
Total Output Error ²	E _{TOT}	$I_{P} = I_{PR(max)}, T_{j} = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±0.8	2	%		
Total Output Error Cor	nponents ³ I	E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)						
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±0.6	1.5	%		
Offset Voltage	V _{OE}	$I_P = 0 \text{ A}, T_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±5	10	mV		
Lifetime Drift Characte	ristics							
Sensitivity Error Lifetime Drift	E sens_drift			±1		%		
Total Output Error Lifetime Drift	E tot_drift			±1		%		



CH70150AU5* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

uniess otherwise specified									
Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit			
Nominal Performance									
Supply Voltage	V _{CC}		4.5	-	5.5	V			
Current-Sensing Range	l PR		0	-	50	А			
Sensitivity	Sens	$I_{PR(min)} < I_{P} < I_{PR(max)}$, VCC = 5V	_	80	_	mV/A			
Zero-Current Output Voltage	V _{IOUT(Q)}	Unidirectional, $I_P = 0 A$, VCC = 5V	_	V _{cc} × 0.1	Ι	V			
Accuracy Performance	9								
Total Output Error ²	E _{TOT}	$I_{P} = I_{PR(max)}, T_{j} = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±0.7	2	%			
Total Output Error Cor	nponents ³ I	E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)							
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±0.7	1.5	%			
Offset Voltage	V _{OE}	$I_{P} = 0 \text{ A}, T_{j} = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±6	10	mV			
Lifetime Drift Characte	ristics								
Sensitivity Error Lifetime Drift	E sens_drift			±1		%			
Total Output Error Lifetime Drift	E tot_drift			±1		%			



CH70150AU3* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

uniess otherwise specified									
Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit			
Nominal Performance									
Supply Voltage	V _{CC}		3	-	3.6	V			
Current-Sensing Range	l PR		0	-	50	А			
Sensitivity	Sens	$I_{PR(min)} < I_{P} < I_{PR(max)}$, VCC = 3.3V	-	52	-	mV/A			
Zero-Current Output Voltage	V _{IOUT(Q)}	Unidirectional, $I_P = 0 A$, VCC = 3.3V	_	0.45	-	V			
Accuracy Performance	9								
Total Output Error ²	E _{TOT}	$I_{P} = I_{PR(max)}, T_{j} = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±0.7	2	%			
Total Output Error Cor	nponents ³ I	E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)							
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±0.7	1.5	%			
Offset Voltage	V _{OE}	$I_P = 0 \text{ A}, T_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±6	10	mV			
Lifetime Drift Characteristics									
Sensitivity Error Lifetime Drift	E sens_drift			±1		%			
Total Output Error Lifetime Drift	E tot_drift			±1		%			



CH70150AB5* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

uniess otnerwise specified									
Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit			
Nominal Performance									
Supply Voltage	V _{cc}		4.5	-	5.5	V			
Current-Sensing Range	l PR		-50	-	50	А			
Sensitivity	Sens	$I_{PR(min)} < I_{P} < I_{PR(max)}$, VCC = 5V	_	40	_	mV/A			
Zero-Current Output Voltage	V _{IOUT(Q)}	Bidirectional, $I_P = 0 A$, VCC = 5V	_	V _{CC} × 0.5	-	V			
Accuracy Performance	9								
Total Output Error ²	E _{TOT}	$I_{P} = I_{PR(max)}, T_{j} = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±0.8	2	%			
Total Output Error Cor	nponents ³ I	E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)							
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±0.6	1.5	%			
Offset Voltage	V _{OE}	$I_P = 0 \text{ A}, T_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±5	10	mV			
Lifetime Drift Characteristics									
Sensitivity Error Lifetime Drift	E sens_drift			±1		%			
Total Output Error Lifetime Drift	E tot_drift			±1		%			



CH70150AB3* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit			
Nominal Performance									
Supply Voltage	V _{cc}		3	-	3.6	V			
Current-Sensing Range	l PR		-50	-	50	А			
Sensitivity	Sens	$ _{PR(min)} < _{P} < _{PR(max)}$, VCC = 3.3V	-	26	-	mV/A			
Zero-Current Output Voltage	V _{IOUT(Q)}	Bidirectional, $I_P = 0 A$, VCC = 3.3V	_	V _{CC} × 0.5	-	V			
Accuracy Performance	•								
Total Output Error ²	E _{TOT}	$I_{P} = I_{PR(max)}, T_{j} = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±0.8	2	%			
Total Output Error Con	nponents ³ I	E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)							
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±0.6	1.5	%			
Offset Voltage	V _{OE}	$I_P = 0 \text{ A}, T_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±5	10	mV			
Lifetime Drift Characteristics									
Sensitivity Error Lifetime Drift	E sens_drift			±1		%			
Total Output Error Lifetime Drift	Etot_drift			±1		%			



CH70150BU5* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

uniess otherwise specified									
Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit			
Nominal Performance									
Supply Voltage	V _{CC}		4.5	-	5.5	V			
Current-Sensing Range	l PR		0	-	50	А			
Sensitivity	Sens	$I_{PR(min)} < I_{P} < I_{PR(max)}$	_	80	_	mV/A			
Zero-Current Output Voltage	V _{IOUT(Q)}	Unidirectional, I _P = 0 A	_	0.5	_	V			
Accuracy Performance	•								
Total Output Error ²	E _{TOT}	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±0.7	2	%			
Total Output Error Con	nponents ³	E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)							
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±0.7	1.5	%			
Offset Voltage	V _{OE}	$I_P = 0 \text{ A}, T_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±6	10	mV			
Lifetime Drift Characteristics									
Sensitivity Error Lifetime Drift	E sens_drift			±1		%			
Total Output Error Lifetime Drift	E tot_drift			±1		%			



CH70150BB5* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

unless otherwise spe	cificu							
Characteristic	Symbol	Test Conditions	Min.	Typ.1	Max.	Unit		
Nominal Performance								
Supply Voltage	V _{CC}		4.5	-	5.5	V		
Current-Sensing Range	l PR		-50	-	50	А		
Sensitivity	Sens	$I_{PR(min)} < I_{P} < I_{PR(max)}$	_	40	_	mV/A		
Zero-Current Output Voltage	V _{IOUT(Q)}	Bidirectional, $I_P = 0 A$	_	2.5	_	V		
Accuracy Performance	•							
Total Output Error ²	E _{TOT}	$I_{P} = I_{PR(max)}, T_{j} = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±0.8	2	%		
Total Output Error Con	nponents ³	E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)						
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±0.6	1.5	%		
Offset Voltage	V _{OE}	$I_P = 0 \text{ A}, T_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±5	10	mV		
Lifetime Drift Characteristics								
Sensitivity Error Lifetime Drift	E sens_drift			±1		%		
Total Output Error Lifetime Drift	E tot_drift			±1		%		



CH70150CU5* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

Characteristic		Test Conditions	Min	Turn 1	Max	l lmit		
Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit		
Nominal Performance								
Supply Voltage	V _{CC}		4.5	-	5.5	V		
Current-Sensing Range	l PR		0	Ι	50	А		
Sensitivity	Sens	$I_{PR(min)} < I_{P} < I_{PR(max)}$	_	52	_	mV/A		
Zero-Current Output Voltage	V _{IOUT(Q)}	Unidirectional, I _P = 0 A	_	0.33	_	V		
Accuracy Performance	•							
Total Output Error ²	E _{TOT}	$I_{P} = I_{PR(max)}, T_{j} = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±0.7	2	%		
Total Output Error Con	nponents ³ I	E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)						
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±0.7	1.5	%		
Offset Voltage	V _{OE}	$I_P = 0 \text{ A}, T_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±6	10	mV		
Lifetime Drift Characteristics								
Sensitivity Error Lifetime Drift	E sens_drift			±1		%		
Total Output Error Lifetime Drift	E tot_drift			±1		%		



CH70150CU3* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Typ.1	Max.	Unit		
Nominal Performance								
Supply Voltage	V _{CC}		3	-	3.6	V		
Current-Sensing Range	l PR		0	_	50	А		
Sensitivity	Sens	$I_{PR(min)} < I_{P} < I_{PR(max)}$	_	52	_	mV/A		
Zero-Current Output Voltage	V _{IOUT(Q)}	Unidirectional, I _P = 0 A	_	0.33	_	V		
Accuracy Performance	9							
Total Output Error ²	E _{TOT}	$I_{P} = I_{PR(max)}, T_{j} = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±0.7	2	%		
Total Output Error Cor		E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)						
Sensitivity Error	Esens	$I_{P} = I_{PR(max)}, T_{j} = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±0.7	1.5	%		
Offset Voltage	V _{OE}	$I_{P} = 0 \text{ A}, T_{j} = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±6	10	mV		
Lifetime Drift Characteristics								
Sensitivity Error Lifetime Drift	E sens_drift			±1		%		
Total Output Error Lifetime Drift	E tot_drift			±1		%		



CH70150CB5* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

uniess otherwise specified									
Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit			
Nominal Performance									
Supply Voltage	V _{cc}		4.5	-	5.5	V			
Current-Sensing Range	l PR		-50	Ι	50	А			
Sensitivity	Sens	$I_{PR(min)} < I_{P} < I_{PR(max)}$	_	26	_	mV/A			
Zero-Current Output Voltage	V _{IOUT(Q)}	Bidirectional, $I_P = 0 A$	_	1.65	_	V			
Accuracy Performance	•								
Total Output Error ²	E _{TOT}	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±0.8	2	%			
Total Output Error Cor	nponents ³ I	E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)							
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±0.6	1.5	%			
Offset Voltage	V _{OE}	$I_P = 0 \text{ A}, T_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±5	10	mV			
Lifetime Drift Characteristics									
Sensitivity Error Lifetime Drift	E sens_drift			±1		%			
Total Output Error Lifetime Drift	E tot_drift			±1		%			



CH70150CB3* Performance Characteristics: TA Range L, valid at Tj = -40°C to 150°C, unless otherwise specified

uniess otherwise specified									
Characteristic	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Unit			
Nominal Performance									
Supply Voltage	V _{CC}		3	-	3.6	V			
Current-Sensing Range	l PR		-50	_	50	А			
Sensitivity	Sens	$ _{PR(min)} < _{P} < _{PR(max)}$	-	26	-	mV/A			
Zero-Current Output Voltage	V _{IOUT(Q)}	Bidirectional, $I_P = 0 A$	_	1.65	_	V			
Accuracy Performance	9								
Total Output Error ²	E _{TOT}	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-2	±0.8	2	%			
Total Output Error Con	nponents ³	E _{TOT} = E _{SENS} + 100 × V _{OE} /(Sens × I _P)							
Sensitivity Error	Esens	$I_P = I_{PR(max)}, T_j = -40^{\circ}C \text{ to } 150^{\circ}C$	-1.5	±0.6	1.5	%			
Offset Voltage	V _{OE}	$I_P = 0 \text{ A}, T_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$	-10	±5	10	mV			
Lifetime Drift Characteristics									
Sensitivity Error Lifetime Drift	Edrift			±1		%			
Total Output Error Lifetime Drift	E tot_drift			±1		%			



6 Application Information

6.1 Estimating Total Error vs. Sensed Current

The Performance Characteristics tables give distribution (\pm 3sigma) values for Total Error at $_{IPR(max)}$; however, one often wants to know what error to expect at a particular current. This can be estimated by using the distribution data for the components of Total Error, Sensitivity Error, and Offset Voltage. The \pm 3 sigma value for Total Error (E_{TOT}) as a function of the sensed current (I_P) is estimated as:

$$E_{TOT}(I_P) = \sqrt{E_{SENS}^2 + \left(\frac{100 \times V_{OE}}{Sens \times I_P}\right)^2}$$

Here, E_{SENS} and V_{OE} are the ±3 sigma values for those error terms. If there is an average sensitivity error or average offset voltage, then the average Total Error is estimated as:

$$E_{TOT_{AVG}}(I_P) = E_{SENS_{AVG}} + \frac{100 \times V_{OE_{AVG}}}{Sens \times I_P}$$

The resulting total error will be a sum of E_{TOT} and E_{TOT_AVG} . Using these equations and the 3 sigma distributions for Sensitivity Error and Offset Voltage, the Total Error versus sensed current (I_P) is below for the CH70120AB. As expected, as one goes towards zero current, the error in percent goes towards infinity due to division by zero.

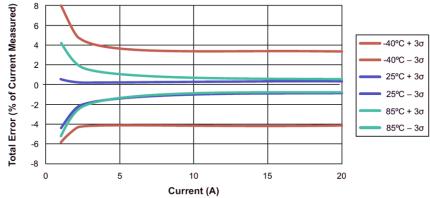


Figure 1: Predicted Total Error as a Function of the Sensed Current for the CH70120AB

6.2 Definitions of accuracy characteristics

Sensitivity (Sens). The change in sensor IC output in response to a 1 A change through the primary conductor. The sensitivity is the product of the magnetic circuit sensitivity (G/A) (1 G = 0.1 mT) and the linear IC amplifier gain (mV/G). The linear IC amplifier gain is programmed at the factory to optimize the sensitivity (mV/A) for the full-scale current of the device.

Nonlinearity (E_{LIN}). The nonlinearity is a measure of how linear the output of the sensor IC is over the full current measurement range. The nonlinearity is calculated as:

$$E_{LIN} = \left\{ 1 - \left[\frac{V_{IOUT}(I_{PR(max)}) - V_{IOUT_{(Q)}}}{2 \times (V_{IOUT}(\frac{I_{PR(max)}}{2}) - V_{IOUT_{(Q)}})} \right] \right\} \times 100(\%)$$

where $V_{IOUT}(I_{PR(max)})$ is the output of the sensor IC with the maximum measurement current flowing through it and $V_{IOUT}(I_{PR(max)}/2)$ is the output of the sensor IC with half of the maximum measurement current flowing through it.

Zero-Current Output Voltage (V_{IOUT(Q})**).** The output of the sensor when the primary current is zero. For a unipolar supply voltage, it nominally remains at $0.5 \times V_{CC}$ for a bidirectional device and $0.1 \times V_{CC}$ for a unidirectional device. For example, in the case of a bidirectional output device, $V_{CC} = 5 V$ translates into $V_{IOUT(Q)} = 2.5 V$. Variation in $V_{IOUT(Q)}$ can be attributed to the resolution of the linear IC quiescent voltage trim and thermal drift.

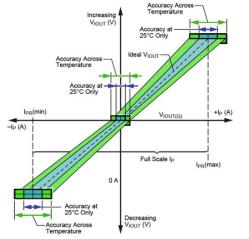


Offset Voltage (V_{OE}). The deviation of the device output from its ideal quiescent value of $0.5 \times V_{CC}$ (bidirectional) or $0.1 \times V_{CC}$ (unidirectional) due to nonmagnetic causes. To convert this voltage to amperes, divide by the device sensitivity, Sens.

Total Output Error (E_{TOT}). The difference between the current measurement from the sensor IC and the actual current (I_P), relative to the actual current. This is equivalent to the difference between the ideal output voltage and the actual output voltage, divided by the ideal sensitivity, relative to the current flowing through the primary conduction path:

$$E_{TOT}(I_P) = \frac{V_{IOUT_ideal}(I_P) - V_{IOUT}(I_P)}{Sens_{ideal}(I_P) \times I_P} \times 100(\%)$$

The Total Output Error incorporates all sources of error and is a function of I_P. At relatively high currents, E_{TOT} will be mostly due to sensitivity error, and at relatively low currents, E_{TOT} will be mostly due to Offset Voltage (V_{OE}). In fact, at I_P = 0, E_{TOT} approaches infinity due to the offset. This is illustrated in Figures 2 and 3. Figure 2 shows a distribution of output voltages versus I_P at 25°C and across temperature. Figure 3 shows the corresponding E_{TOT} versus I_P.



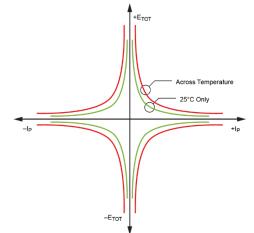


Figure 2: Output Voltage versus Sensed Current

Figure3: Total Output Error versus Sensed Current

Sensitivity Ratiometry Coefficient (SENS_RAT_COEF). The coefficient defines how the sensitivity scales with V_{CC}. The ideal coefficient is 1, meaning the sensitivity scales proportionally with V_{CC}. A 10% increase in V_{CC} results in a 10% increase in sensitivity. A coefficient of 1.1 means that the sensitivity increases by 10% more than the ideal proportionality case. This means that a 10% increase in V_{CC} results in an 11% increase in sensitivity. This relationship is described by the following equation:

$$Sens(V_{CC}) = Sens(5V) \left[1 + \frac{(V_{CC} - 5V) \times SENS_RAT_COEF}{5V} \right]$$

This can be rearranged to define the sensitivity ratiometry coefficient as:

$$SENS_{RAT_{COEF}} = \left[\frac{Sens(V_{CC})}{Sens(5V)} - 1\right] \times \frac{5V}{V_{CC} - 5V}$$

Zero-Current Output Ratiometry Coefficient (QVO_RAT_COEF). The coefficient defines how the zero-current output voltage scales with V_{cc}. The ideal coefficient is 1, meaning the output voltage scales proportionally with V_{cc}, always being equal to V_{cc}/2. A coefficient of 1.1 means that the zero-current output voltage increases by 10% more than the ideal proportionality case. This means that a 10% increase in V_{cc} results in an 11% increase in the zero-current output voltage. This relationship is described by the following equation:

$$VIOUTQ(V_{CC}) = VIOUTQ(5V) \left[1 + \frac{(V_{CC} - 5V) \times QVO_RAT_COEF}{5V} \right]$$

This can be rearranged to define the zero-current output ratiometry coefficient as:

$$QVO_RAT_COEF = \left[\frac{VIOUTQ(V_{CC})}{VIOUTQ(5V)} - 1\right] \times \frac{5V}{V_{CC} - 5V}$$



6.3 Definitions of dynamic response characteristics

Power-On Time (t_{PO}). When the supply is ramped to its operating voltage, the device requires a finite time to power its internal components before responding to an input magnetic field. Power-On Time, t_{PO} , is defined as the time it takes for the output voltage to settle within ±10% of its steady-state value under an applied magnetic field, after the power supply has reached its minimum specified operating voltage, $V_{CC(min)}$, as shown in the chart at right.

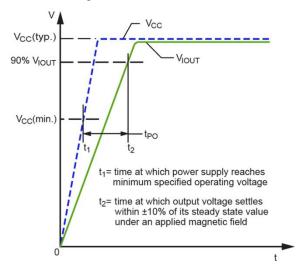
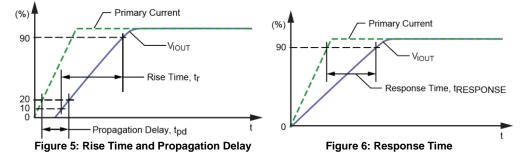


Figure 4: Power-On Time

Rise Time (t_r**).** The time interval between a) when the sensor IC reaches 10% of its full-scale value, and b) when it reaches 90% of its full-scale value. The rise time to a step response is used to derive the bandwidth of the current sensor IC, in which $f(-3 \text{ dB}) = 0.35 / \text{t}_r$. Both t_r and t_{RESPONSE} are detrimentally affected by eddy-current losses observed in the conductive IC ground plane.

Propagation Delay (t_{pd}). The propagation delay is measured as the time interval a) when the primary current signal reaches 20% of its final value, and b) when the device reaches 20% of its output corresponding to the applied current.



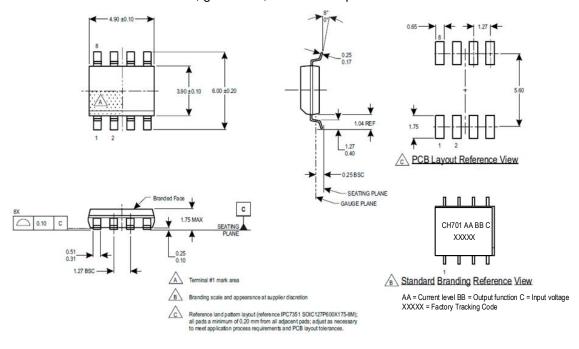
Response Time (t_{RESPONSE}). The time interval between a) when the primary current signal reaches 90% of its final value, and b) when the device reaches 90% of its output corresponding to the applied current.



7 Package Information

For Reference Only – Not for Tooling Use

(Reference MS-012AA) Dimensions in millimeters – NOT TO SCALE Dimensions exclusive of mold flash, gate burrs, and dambar protrusions







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